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Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	-30				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0081				
$R_{DS(on)}$ (Ω) at $V_{GS} = -4.5 \text{ V}$	0.0170				
I _D (A)	-75				
Configuration	Single				
Package	PowerPAK SO-8L				

FEATURES

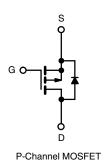
- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified c
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE





ABSOLUE MAXIMUM RATINGS (7	$T_C = 25 ^{\circ}C$, unless	otherwise noted)			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V_{DS}	-30	V	
Gate-Source Voltage		V_{GS}	± 20	V	
Continuous Drain Current	T _C = 25 °C	1	-75		
Continuous Drain Current	T _C = 125 °C	I _D	-45		
Continuous Source Current (Diode Conduction)		I _S	-75	Α	
Pulsed Drain Current a		I _{DM}	-200		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	-40		
Single Pulse Avalanche Energy	L = 0.1 IIII	E _{AS}	70	mJ	
Maximum Power Dissipation a	T _C = 25 °C	P _D	83	W	
Maximum Fower Dissipation a	T _C = 125 °C	r _D	27	VV	
$T_{\rm C} = 125 ^{\circ}{\rm C}$ Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	
Soldering Recommendations (Peak Temperatu	re) ^{d, e}		260	C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^b	R_{thJA}	65	°C/W
Junction-to-Case (Drain)		R_{thJC}	1.8	C/VV

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. When mounted on 1" square PCB (FR4 material).
- c. Parametric verification ongoing.
- d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.



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PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT
Static					L		ı
Drain-Source Breakdown Voltage	V _{DS}	V _{GS}	= 0, I _D = -250 μA	-30	-	-	V
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} =	V_{GS} , $I_{D} = -250 \mu A$	-1.5	-2.0	-2.5	\ \
Gate-Source Leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -30 V	-	-	-1	
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -30 V, T _J = 125 °C	-	-	-50	μΑ
		V _{GS} = 0 V	V _{DS} = -30 V, T _J = 175 °C	-	-	-150	
On-State Drain Current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 \text{ V}$	-30	-	-	Α
		V _{GS} = -10 V	I _D = -16 A	-	0.0064	0.0081	
Drain Course On State Besistance		V _{GS} = -4.5 V	I _D = -12 A	-	0.0118	0.0170	Ω
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = -10 V	I _D = -16 A, T _J = 125 °C	-	0.0085	-	
		V _{GS} = -10 V	I _D = -16 A, T _J = 175 °C	-	0.0100	-	
Forward Transconductance b	9 _{fs}	V _{DS} =	-15 V, I _D = -13.8 A	-	40	-	S
Dynamic ^b							
Input Capacitance	C _{iss}			-	3683	4877	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	$V_{DS} = -15 \text{ V}, f = 1 \text{ MHz}$	-	775	1072	pF
Reverse Transfer Capacitance	C _{rss}			-	561	695	
Total Gate Charge ^c	Qg			-	72	108	
Gate-Source Charge c	Q_{gs}	$V_{GS} = -10 \text{ V}$	$V_{DS} = -15 \text{ V}, I_{D} = -15 \text{ A}$	-	12	-	nC
Gate-Drain Charge ^c	Q_{gd}			-	20	-	
Gate Resistance	R_g		f = 1 MHz	0.5	1.1	2	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	17	26	
Rise Time ^c	t _r	VDD = -20 V, NL = 13 32		21	31	ne	
Turn-Off Delay Time ^c	t _{d(off)}	I _D ≅ -1 A, \	$V_{\rm GEN} = -10$ V, $R_{\rm g} = 6 \Omega$	-	79	110	ns
Fall Time ^c	t _f			-	49	69	
Source-Drain Diode Ratings and Chara	icteristics ^b						
Pulsed Current ^a	I _{SM}			-	-	-200	Α
	V_{SD}	I _F = -10 A, V _{GS} = 0			-0.8	-1.2	V

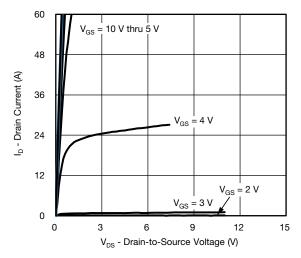
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

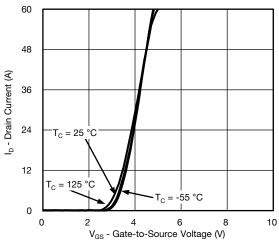
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



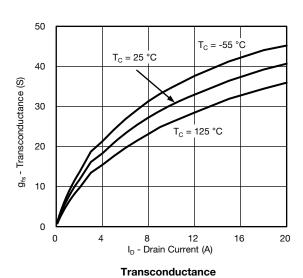
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

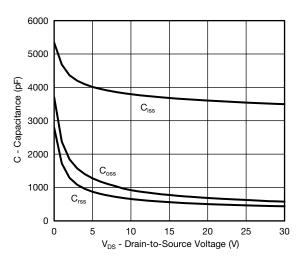


Output Characteristics

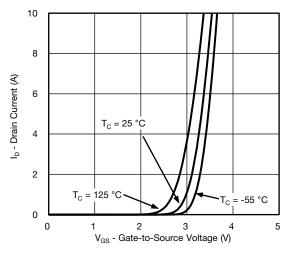


Transfer Characteristics

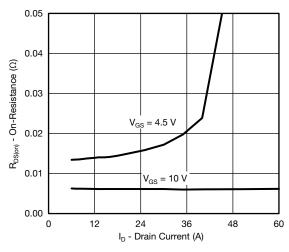




Capacitance



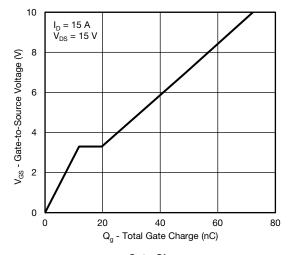
Transfer Characteristics



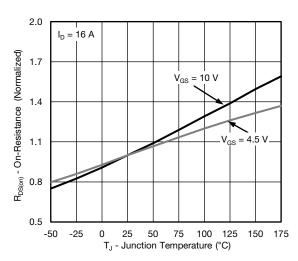
On-Resistance vs. Drain Current



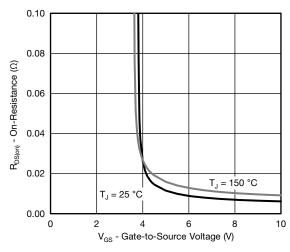
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Gate Charge

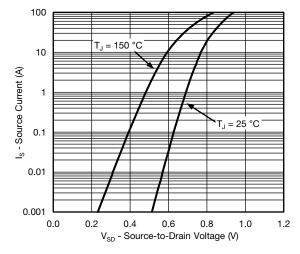


On-Resistance vs. Junction Temperature

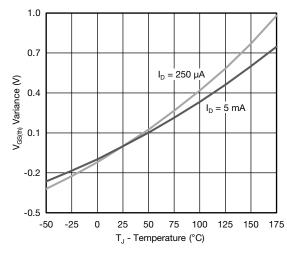


On-Resistance vs. Gate-to-Source Voltage

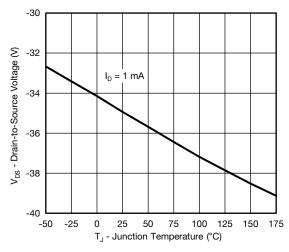
S15-2147-Rev. A, 14-Sep-15



Source Drain Diode Forward Voltage



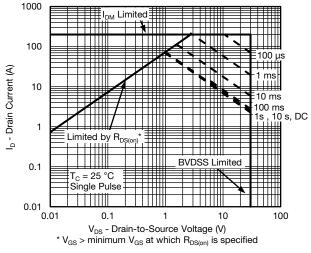
Threshold Voltage



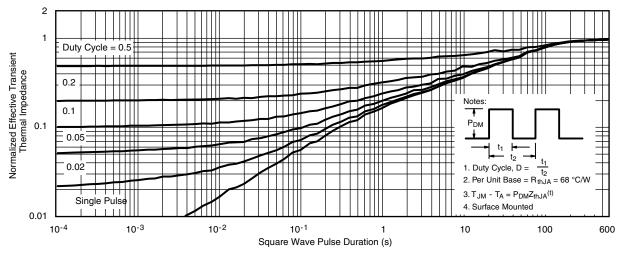
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



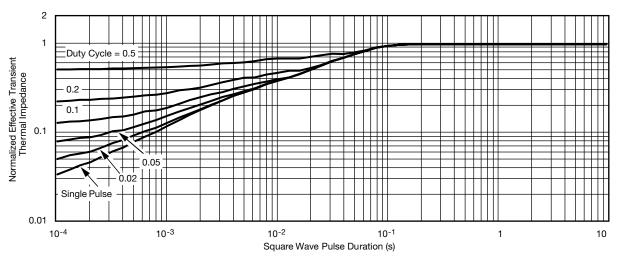
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

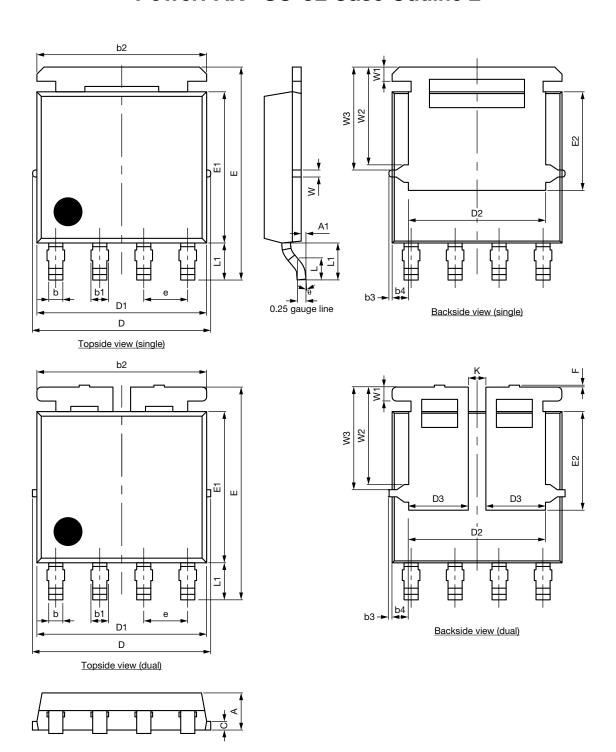
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62917.



PowerPAK® SO-8L Case Outline 2



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DIM.		MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
А	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC			0.050 BSC		
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K		0.51			0.020		
W		0.23		0.009			
W1	0.41		0.016				
W2	2.82		0.111				
W3	2.96			0.117			
θ	0°	-	10°	0°	-	10°	

ECN: C21-1498-Rev. C, 01-Nov-2021

DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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